

DFN0603Transient Voltage Suppressors ESD Protection Diode

Absolute Maximum Ratings T_A = 25°C unless otherwise noted

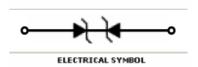
Symbol	Parameter	Value	Units
PD	Total Power Dissipation on FR-5 Broad	150	mW
T _L	Max Lead Solder Temperature range (10 Second Duration)	260	°C
T_{stg}	Storage Temperature Range	-55 to +150	°C
TJ	Junction Temperature	Temperature +150	
ESD	IEC61000-4-2 Air Discharge Contact Discharge	±15 ±8	KV
EFT	IEC61000-4-4	40	Α
ESD	Per Human Body Model	16	KV

These ratings are limiting values above which the serviceability of the diode may be impaired.

Green Product



DFN0603 Package



Specification Features:

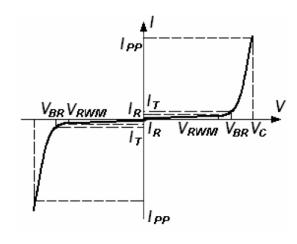
- Capacitance Typ. 15pF
- Small Body Outline Dimensions
- Low Leakage Current
- Response Time is Typically < 1ns
- ESD Rating of Class 3 (>16kV) per Human Body Model
- RoHS Compliant
- Green EMC
- Matte Tin(Sn) Lead Finish
- Weight: approx. 0.24mg

DEVICE MARKING CODES:

Device Type	Marking	Shipping		
ESD11D5V0C		10,000/Reel		

Electrical Parameter

Symbol	Parameter					
I _{PP}	Maximum Reverse Peak Pulse Current					
V _C	Clamping Voltage @ I _{PP}					
V_{RWM}	Working Peak Reverse Voltage					
I _R	Maximum reverse Leakage Current @ V _{RWM}					
I _T	Test Current					
V_{BR}	Breakdowm Voltage @ I _T					



Number: DB-312 Mar. 2019, Revision B



SEMICONDUCTOR

Electrical Characteristics (T_A = 25°C unless otherwise noted)

Device Type	V _{RWM} (Volts)	I _R @ V _{RWM} (μΑ)	(Not	@ I _T te 1) olts)	I _T (mA)	V _c @ I _{PP} *=1A (Volts)	V _c @ Max I _{PP} (Volts)	Max I _{PP} *	C @ V _R = 0V, f = 1MHz (pF)
	Max	Max	Min	Max		Max	Max		Тур.
ESD11D5V0C	5.0	0.5	5.6		1.0	9.8	12.5	5.5	15

SURGE CURRENT WAVEFORM:

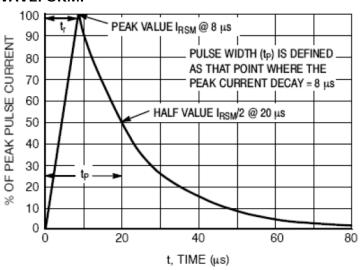
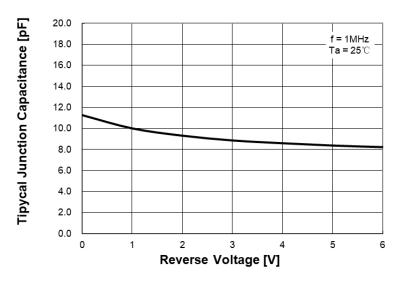


Figure 1. 8 x 20 µs Pulse Waveform

CAPACITANCE CURVE:



Number: DB-312 Mar. 2019, Revision B

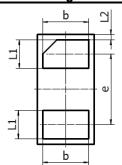
^{*} Surge current waveform per Figure 1.

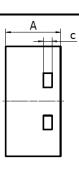
Note 1: V_{BR} is measured with a pulse test current I_T at an ambient temperature of 25°C.

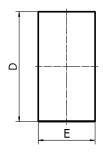


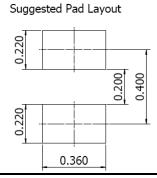
SEMICONDUCTOR

DFN0603 Package Outline









DIM	MILLIM	ETERS	INCHES		
	MIN	MAX	MIN	MAX	
Α	0.27	0.35	0.011	0.013	
D	0.57	0.67	0.022	0.026	
E	0.27	0.37	0.011	0.015	
b	0.225	0.295	0.009	0.012	
С	0.050REF		0.002REF		
е	0.365	0.435	0.014	0.017	
L1	0125	0.195	0.005	0.008	
L2	0.030	REF	0.001REF		

Number: DB-312 Mar. 2019, Revision B





NOTICE

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The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), Tak Cheong Semiconductor Co., Ltd., or anyone on its behalf, assumes no responsibility or liability for any damagers resulting from such improper use of sale.

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Number: DB-100 April 14, 2008 / A